0.40+0.10

(0.95)1.9+0

2.90+0.20

0 Ľ

50 50 0+8 0 Unit: mm

0.16+0.10

1: Base 2: Emitter 3. Collector EIAJ: SC-59 Mini3-G1 Package

# 2SB0779 (2SB779)

# Silicon PNP epitaxial planar type

For low-frequency output amplification

#### Features

- Low collector-emitter saturation voltage V<sub>CE(sat)</sub>
- Satisfactory linearity of forward current transfer ratio h<sub>FE</sub> at the low collector voltage
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

#### ■ Absolute Maximum Ratings T<sub>a</sub> = 25°C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-25	V	0000
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-20	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	-7	V	
Collector current	Ic	-500	mA	Marking Symbol: 1A
Peak collector current	I <sub>CP</sub>	-1	A	
Collector power dissipation	P <sub>C</sub>	200	mW	xe <sup>2</sup>
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	all 150

### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Collector current	Ic	-500	mA Mar	king Symbol	: IA		
Peak collector current	I <sub>CP</sub>	-1	A	X			
Collector power dissipation	P <sub>C</sub>	200	mW	xes	$\sim$		
Junction temperature	Tj	150	°C	10,10	2 <sup>1</sup>		
Storage temperature	T <sub>stg</sub> -	-55 to +150	°C	N JSC'			
Peak collector current $I_{CP}$ $-1$ ACollector power dissipation $P_C$ 200mWJunction temperature $T_j$ 150°CStorage temperature $T_{stg}$ $-55$ to $+150$ °CElectrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$ $T_a = 25^{\circ}C \pm 3^{\circ}C$							
Parameter	Symbol		Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>СВО</sub>	$I_{C} = -10 \ \mu$	A, $I_E = 0$	-25			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = -1  {\rm m}A$	$\mathbf{A}_{\mathbf{B}} = 0$	-20			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = -100$	A, $I_{c} \neq 0$	-7			V
Collector-base cutoff current (Emitter open)	І <sub>СВО</sub>	V <sub>CB</sub> = −25	$\mathbf{V}, \mathbf{I}_{\mathrm{E}} = 0$			-100	nA
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = -20$	$V, I_{B} = 0$			-1	μΑ
Forward current transfer ratio <sup>*1</sup>	h <sub>FE1</sub> *	$V_{CE} = -2$	V, $I_{\rm C} = -500 \text{ mA}$	90		220	
	hFE2	$V_{CE} = -2$ V	$V, I_{C} = -1 A$	25			
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_{\rm C} = -500$	mA, $I_B = -50 \text{ mA}$		- 0.2	- 0.4	V
Base-emitter saturation voltage *	V <sub>BE(sat)</sub>	$I_{\rm C} = -500$	mA, $I_B = -50 \text{ mA}$			-1.2	V
Transition frequency	f <sub>T</sub>	$V_{CB} = -10$	V, $I_E = 50$ mA, $f = 200$	MHz	150		MHz
Collector output capacitance (Common-emitter reverse transfer)	C <sub>ob</sub>	$V_{CB} = -10$	V, $I_E = 0$ , $f = 1$ MHz		15		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

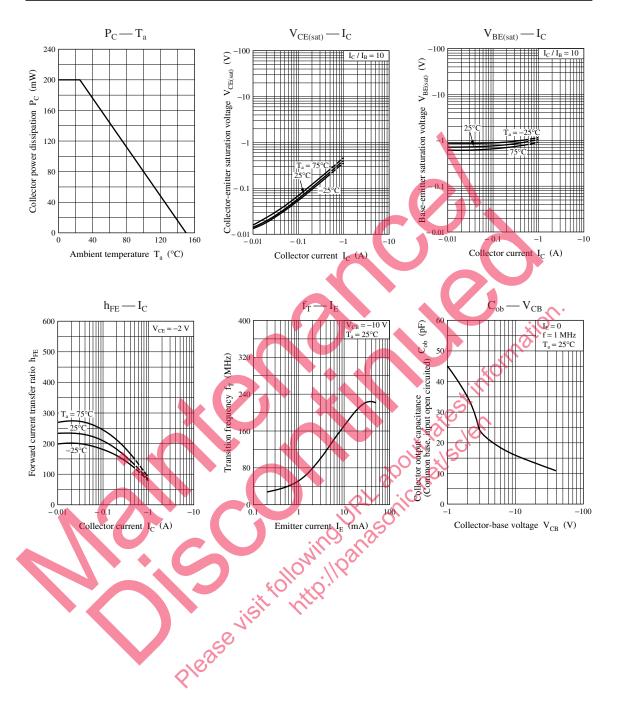
2. \*1: Pulse measurement 1 1 . . . . . .

*2: Rank classification						
Rank	Q	R				
h <sub>FE1</sub>	90 to 155	130 to 220				

Note) The part number in the parenthesis shows conventional part number.

## 2SB0779





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